
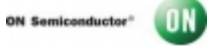







	<h2>NTB60N06G</h2>
	<p>Hersteller-Teilenummer: NTB60N06G</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 60V 60A D2PAK</p> <p>Datenblätter:  NTB60N06G.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 33404 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTB60N06G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 60V 60A D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	33404 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (Tj)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D2PAK
Verlustleistung (max)	2.4W (Ta), 150W (Tj)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	60A (Ta)
Rds On (Max) @ Id, Vgs	14 mOhm @ 30A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	81nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	3220pF @ 25V
Verpackung	Tube



















































NTB60N06G ist neu im Original, Suche NTB60N06G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTB60N06G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTB60N06G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTB5860NT4G AMI Semiconductor / ON Semiconductor NTB5860NT4G ON</p>	 <p>NTB60N06 ON NTB60N06 ON</p>	 <p>NTB60N06LT4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 60A D2PAK</p>	 <p>NTB60N06LT4 AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 60A D2PAK</p>
 <p>NTB5605T4G AMI Semiconductor / ON Semiconductor MOSFET P-CH 60V 18.5A D2PAK</p>	 <p>NTB60N06LG AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 60A D2PAK</p>	 <p>NTB60N06L AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 60A D2PAK</p>	 <p>NTB5605PT4 AMI Semiconductor / ON Semiconductor MOSFET P-CH 60V 18.5A D2PAK</p>

heiße Teile

Mehr

 NTB45N06LT4	 NTB45N06LT4G	 NTB45N06T4	 NTB45N06T4G	 NTB52N10
 NTB52N10G	 NTB52N10T4G	 NTB5404N	 NTB5404NT4G	 NTB5405N
 NTB5405NG	 NTB5405NT4G	 NTB5411N	 NTB5411NG	 NTB5411NT4G
 NTB5411NUTUMC	 NTB5412NT4G	 NTB5426N	 NTB5426NT4G	 NTB5605P
 NTB5605PG	 NTB5605PT4	 NTB5605PT4G	 NTB5605T4G	 NTB60N06
 NTB60N06L	 NTB60N06LG	 NTB60N06LT4	 NTB60N06LT4G	 NTB60N06T4G
 NTB6410AN	 NTB6410ANG	 NTB6410ANT4G	 NTB6411AN	 NTB6411ANG
 NTB6411ANT4G	 NTB6412AN	 NTB6412ANG	 NTB6412ANT4G	 NTB6413AN
 NTB6413ANG	 NTB6413ANT4G	 NTB6448ANG	 NTB6448ANT4G	 NTB65N02RG
 NTB65N02RT4	 NTB65N02RT4G	 NTB75N03	 NTB75N03-06T4G	 NTB75N03-6G

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited